

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Munir H. Nayfeh

Serial No.:

09/496,506

Conf. No.:

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Filed:

February 2, 2000

For:

SILICON NANOPARTICLE FIELD

EFFECT TRANSISTOR AND

TRANSISTOR MEMORY DEVICE

Art Unit:

2811

Examiner:

Sara W. Crane

I hereby certify that this paper is being deposited with the United States Postal Service as FIRST-CLASS mail in an envelope addressed to: Mail Stop AMENDMENT, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this date.

April 8, 2005

Date

F-CLASS.WCM Appr. February 20, 1998

Attorney for Applicant

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Dear Sir:

This IDS is submitted under 37 C.F.R. §1.97(c), after the C.F.R. §1.97(b) time period, but before the mail date of a Final Office Action or a Notice of Allowance (whichever occurs first), with either:

- (a) a statement under 37 C.F.R. §1.97(e); or
- (b) the \$180.00 fee under 37 C.F.R. §1.17(p).

Applicant(s) submit herewith Form PTO-1449 (Information Disclosure Citation) together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 C.F.R. §1.56. Applicant(s) respectfully submit that the citation of any reference on Form PTO-1449 does not constitute an admission that the reference qualifies as prior art.

It is requested that the information disclosed on the enclosed Form PTO-1449 be made of record in this application.

- (X) Statement Under 37 C.F.R. §1.97(e):
  - The enclosed references were cited in a Communication issued by a foreign Patent Office (copy (X) enclosed). Applicant(s) hereby certify that each item of information cited on the enclosed Form PTO-1449 was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three (3) months prior to the filing of this Information Disclosure Statement.
  - Applicant(s) hereby certify that no item of information cited on the enclosed Form PTO-1449 was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing below after making reasonable inquiry, no item of information cited on the enclosed Form PTO-1449 was known to any individual designated in §1.56(c) more than three months prior to the filing of this Information Disclosure Statement.

Respectfully submitted,

GREER, BURNS & CRAIN, LTD.

( ) Enclosed is a check for \$180.00 to cover the fee as set forth in 37 C.F.R. § 1.17(p).

The Commissioner is hereby authorized to charge any additional fees which may be required to this application under 37 C.F.R. §§1.16-1.17, or to credit any overpayment, to Deposit Account No. 07-2069. A duplicate copy of this sheet is enclosed.

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| Form PTO-1449 U.S. Department of Commerce (Rev. 8-88) Patent and Trademark Office  |  |              |                     | Attorney Docket No.: 1201.63407       |           | Serial No.: 09/496,506 |                            |        |
| INFORM   | ATION DISCLOSURE CITA  | TION APR 1 1 | 1 2005              | Applicant: Munir H. Nayfeh            |           |                        |                            |        |
| Form PTO-1449 U.S. Department of Commerce (Rev. 8-88) Patent and Trademark Office  INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)  U.S. PATENT DOCUMENTS  |  |              | 1 2805 3 <i>Day</i> | Filing Date: February 2, 2000         |           | Group: 2811            |                            |        |
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